

TL062, TL062A, TL062B

Low-power JFET dual operational amplifiers

Datasheet -production data

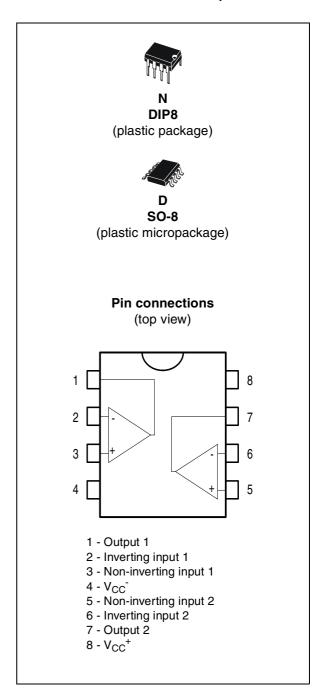
Features

- Very low power consumption: 200 µA
- Wide common-mode (up to V_{CC}⁺) and differential voltage ranges
- Low input bias and offset currents
- Output short-circuit protection
- High input impedance JFET input stage
- Internal frequency compensation
- Latch up free operation
- High slew rate: 3.5 V/µs

Description

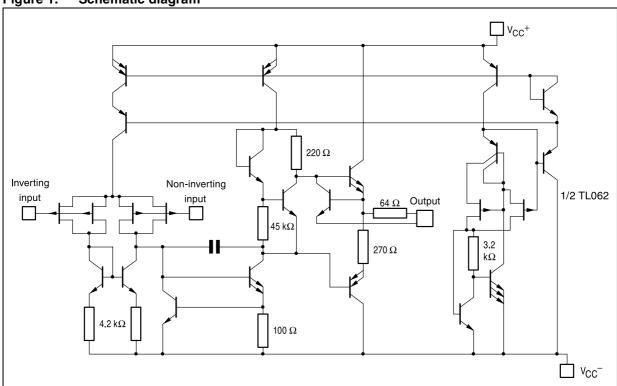
The TL062, TL062A and TL062B devices are high-speed JFET input single operational amplifiers. Each of these JFET input operational amplifiers incorporates well matched, high-voltage JFET and bipolar transistors in a monolithic integrated circuit.

The devices feature high slew rates, low input bias and offset currents, and a low offset voltage temperature coefficient.



1 Schematic diagram

Figure 1. Schematic diagram



2 Absolute maximum ratings and operating conditions

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage ⁽¹⁾	±18	V
Vi	Input voltage ⁽²⁾	±15	٧
V _{id}	Differential input voltage ⁽³⁾	±30	٧
P _{tot}	Power dissipation	680	mW
	Output short-circuit duration ⁽⁴⁾	Infinite	
T _{stg}	Storage temperature range		°C
R _{thja}	Thermal resistance junction-to-ambient ⁽⁵⁾ , ⁽⁶⁾ SO-8 DIP8	125 85	°C/W
R _{thjc}	Thermal resistance junction-to-case ⁽⁵⁾ , (6) SO-8 DIP8	40 41	°C/W
	HBM: human body model ⁽⁷⁾	900	V
ESD	MM: machine model ⁽⁸⁾	150	V
	CDM: charged device model ⁽⁹⁾	1.5	kV

All voltage values, except differential voltage, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between V_{CC}⁺ and V_{CC}⁻.

- 3. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
- The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.
- 5. Short-circuits can cause excessive heating and destructive dissipation.
- 6. R_{th} are typical values.
- 7. Human body model: 100 pF discharged through a 1.5 $k\Omega$ resistor between two pins of the device, done for all couples of pin combinations with other pins floating.
- Machine model: a 200 pF capacitor is charged to the specified voltage, then discharged directly between
 two pins of the device with no external series resistor (internal resistor < 5 Ω), done for all couples of pin
 combinations with other pins floating.
- Charged device model: all pins plus package are charged together to the specified voltage and then discharged directly to ground.

Table 2. Operating conditions

Symbol	Parameter	TL062I, AI, BI	Unit	
V _{CC}	Supply voltage range	6 to	V	
T _{oper}	Operating free air temperature range	-40 to +105 0 to +70		°C



^{2.} The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.

3 Electrical characteristics

Table 3. $V_{CC} = \pm 15 \text{ V}$, $T_{amb} = +25 ^{\circ}\text{C}$ (unless otherwise specified)

Cumbal	Parameter		TL062I		TL062C			I I m i A
Symbol	r al allietei		Тур.	Max.	Min.	Тур.	Max.	Unit
V _{io}	Input offset voltage (R _S = 50 Ω) $T_{amb} = +25 ^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		3	6 9		3	15 20	mV
DV _{io}	Temperature coefficient of input offset voltage ($R_S = 50 \Omega$)		10			10		μV/°C
l _{io}	Input offset current ⁽¹⁾ $T_{amb} = +25 \text{ °C}$ $T_{min} \le T_{amb} \le T_{max}$		5	100 10		5	200 5	pA nA
l _{ib}	Input bias current ⁽¹⁾ $T_{amb} = +25 ^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		30	200 20		30	400 10	pA nA
V _{icm}	Input common mode voltage range	±11.5	+15 -12		±11.5	+15 -12		V
V _{opp}	Output voltage swing ($R_L = 10 \text{ k}\Omega$) $T_{amb} = +25 \text{ °C}$ $T_{min} \le T_{amb} \le T_{max}$	20 20	27		20 20	27		V
A _{vd}	Large signal voltage gain $\begin{aligned} R_L &= 10 \text{ k}\Omega \text{ V}_o = \pm 10 \text{ V}, \\ T_{amb} &= +25 \text{ °C} \\ T_{min} &\leq T_{amb} \leq T_{max} \end{aligned}$	4 4	6		3	6		V/mV
GBP	Gain bandwidth product T_{amb} = +25 °C, R_L =10 kΩ C_L = 100 pF		1			1		MHz
R _i	Input resistance		10 ¹²			10 ¹²		Ω
CMR	Common mode rejection ratio $R_S = 50 \ \Omega$	80	86		70	76		dB
SVR	Supply voltage rejection ratio $R_S = 50 \; \Omega$	80	95		70	95		dB
I _{CC}	Supply current, no load T _{amb} = +25 °C, no load, no signal		200	250		200	250	μА
V ₀₁ /V ₀₂	Channel separation A _V = 100, T _{amb} = 25 °C		120			120		dB
P _D	Total power consumption T _{amb} = +25 °C, no load, no signal		6	7.5		6	7.5	mW
SR	Slew rate V_i = 10 V, R_L = 10 k Ω , C_L = 100 pF, A_v = 1	1.5	3.5		1.5	3.5		V/μs

Table 3. $V_{CC} = \pm 15 \text{ V}$, $T_{amb} = +25 ^{\circ}\text{C}$ (unless otherwise specified) (continued)

Cumbal	Parameter	TL062I			TL062C			Unit
Symbol	raiailletei		Тур.	Max.	Min.	Тур.	Max.	Offic
t _r	Rise time $V_i = 20 \text{ mV}, \ R_L = 10 \text{ k}\Omega, \\ C_L = 100 \text{ pF}, \ A_V = 1$		0.2			0.2		μs
K _{ov}	Overshoot factor (see <i>Figure 15</i>) $V_i = 20 \text{ mV}, R_L = 10 \text{ k}\Omega, C_L = 100 \text{ pF}, A_V = 1$		10			10		%
e _n	Equivalent input noise voltage $R_S = 100 \ \Omega, \ f = 1 \ kHz$		42			42		$\frac{\text{nV}}{\sqrt{\text{Hz}}}$

The input bias currents of a FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive. Pulse techniques must be used that will maintain the junction temperature as close to the ambient temperature as possible.

Table 4. $V_{CC} = \pm 15 \text{ V}, T_{amb} = +25 ^{\circ}\text{C} \text{ (unless otherwise specified)}$

Symbol	Parameter	TL	062AC,	Al	TL062BC, BI			Unit
Syllibol	Farameter		Тур.	Max.	Min.	Тур.	Max.	Oille
V _{io}	Input offset voltage ($R_S = 50 \Omega$) $T_{amb} = +25 ^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		3	3 7.5		2	3 5	mV
DV _{io}	Temperature coefficient of input offset voltage ($R_S = 50 \Omega$)		10			10		μV/°C
I _{io}	Input offset current ⁽¹⁾ $T_{amb} = +25 \text{ °C}$ $T_{min} \leq T_{amb} \leq T_{max}$		5	100 3		5	100 3	pA nA
I _{ib}	Input bias current ⁽¹⁾ $T_{amb} = +25 \text{ °C}$ $T_{min} \le T_{amb} \le T_{max}$		30	200 7		30	200 7	nA
V _{icm}	Input common mode voltage range	±11.5	+15 -12		±11.5	+15 -12		
V _{opp}	Output voltage swing (R _L = 10 k Ω) T_{amb} = +25 °C $T_{min} \le T_{amb} \le T_{max}$	20 20	27		20 20	27		V
A _{vd}	Large signal voltage gain $\begin{aligned} R_L &= 10 \text{ k}\Omega \text{ V}_o = \pm 10 \text{ V}, \\ T_{amb} &= +25 \text{ °C} \\ T_{min} &\leq T_{amb} \leq T_{max} \end{aligned}$	4 4	6		4 4	6		V/mV
GBP	Gain bandwidth product T_{amb} = +25 °C, R_L =10 k Ω , C_L = 100 pF		1			1		MHz
R _i	Input resistance		10 ¹²			10 ¹²		Ω
CMR	Common mode rejection ratio $R_S = 50 \ \Omega$	80	86		80	86		dB
SVR	Supply voltage rejection ratio $R_S = 50 \ \Omega$	80	95		80	95		dB

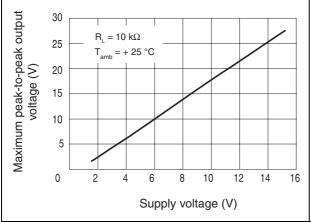
Table 4. $V_{CC} = \pm 15 \text{ V}$, $T_{amb} = +25 ^{\circ}\text{C}$ (unless otherwise specified) (continued)

Symbol	Parameter	TL062AC, AI			TL062BC, BI			Unit
Symbol	Fai ameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Onit
I _{CC}	Supply current, no load $T_{amb} = +25$ °C, no load, no signal		200	250		200	250	μА
V ₀₁ /V ₀₂	Channel separation $A_V = 100$, $T_{amb} = +25$ °C		120			120		
P _D	Total power consumption $T_{amb} = +25 ^{\circ}C$, no load, no signal		6	7.5		6	7.5	mW
SR	Slew rate $V_i = 10 \text{ V}, \text{ R}_L = 10 \text{ k}\Omega, \text{ C}_L = 100 \text{ pF}, \text{ A}_V = 1$	1.5	3.5		1.5	3.5		V/μs
t _r	Rise time $V_i = 20$ mV, $R_L = 10$ k Ω , $C_L = 100$ pF, $A_v = 1$		0.2			0.2		μs
K _{ov}	Overshoot factor (see Figure 15) $V_i = 20 \text{ mV}, R_L = 10 \text{ k}\Omega, C_L = 100 \text{ pF}, A_V = 1$		10			10		%
e _n	Equivalent input noise voltage $R_S = 100 \ \Omega$, $f = 1 \ kHz$		42			42		<u>nV</u> √Hz

The input bias currents of a FET-input operational amplifier are normal junction reverse currents, which are temperature sensitive. Pulse techniques must be used that will maintain the junction temperature as close to the ambient temperature as possible.

Figure 2. Maximum peak-to-peak output voltage versus supply voltage

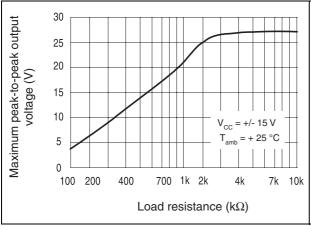
Figure 3. Maximum peak-to-peak output voltage versus free air temperature



30 Maximum peak-to-peak output voltage (V) 25 20 15 $V_{CC} = +/-15 \text{ V}$ 10 $R_1 = 10 \text{ k}\Omega$ 5 0 -75 -50 50 75 -25 25 -50 125 Free air temperature (°C)

Figure 4. Maximum peak-to-peak output voltage versus load resistance

Figure 5. Maximum peak-to-peak output voltage versus frequency



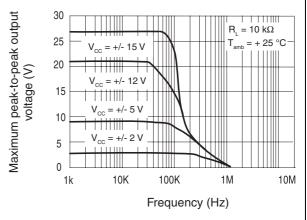
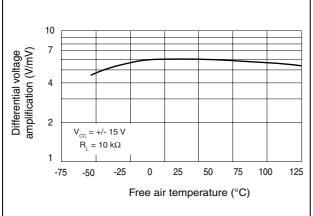


Figure 6. Differential voltage amplification versus free air temperature

Figure 7. Large signal differential voltage amplification and phase shift versus frequency



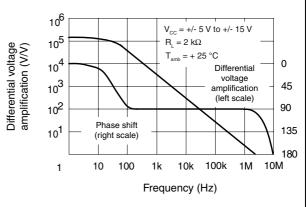
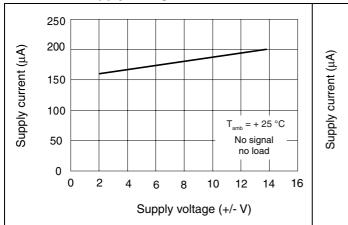


Figure 8. Supply current per amplifier versus Figure 9. Supply current per amplifier versus supply voltage free air temperature



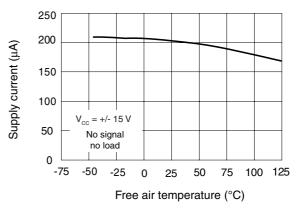
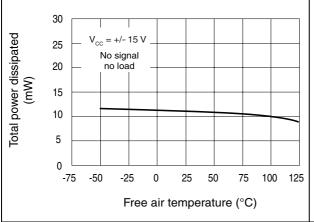


Figure 10. Total power dissipated versus free Figure 11. Common-mode rejection ratio air temperature versus free air temperature



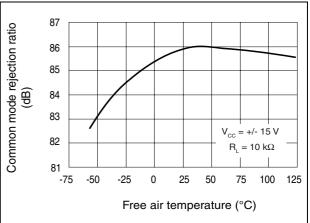
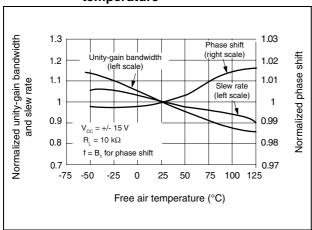
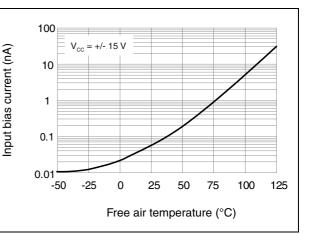


Figure 12. Normalized unity gain bandwidth slew rate and phase shift versus temperature

Figure 13. Input bias current versus free air temperature





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Figure 14. Voltage follower large signal pulse Figure 15. Output voltage versus elapsed time response

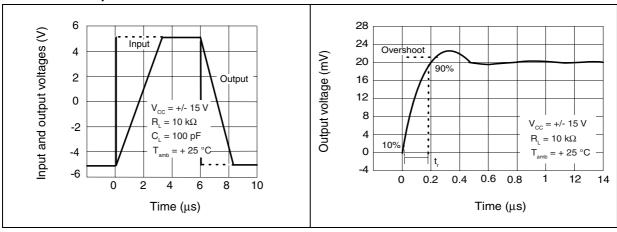
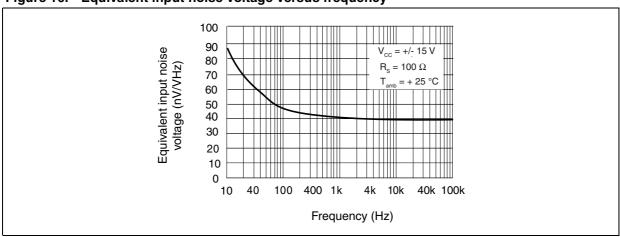


Figure 16. Equivalent input noise voltage versus frequency



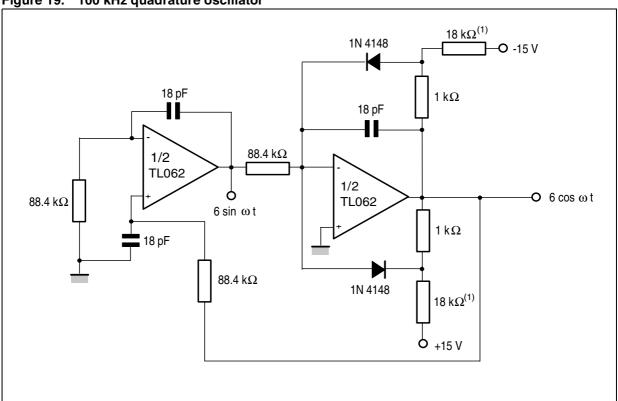
Parameter measurement information

Figure 17. Voltage follower

Figure 18. Gain of 10 inverting amplifier 10 $k\Omega$ $1 \ k\Omega$ 1/2 1/2 TL062 TL062 ⊖ e_o $C_L = 100 pF$ $R_L = 10 \text{ k}\Omega$ $C_{L} = 100 \text{ pF}$

Typical applications 4

Figure 19. 100 kHz quadrature oscillator



1. These resistor values may be adjusted for a symmetrical output.

5 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

5.1 DIP8 package information

Figure 20. DIP8 package outline

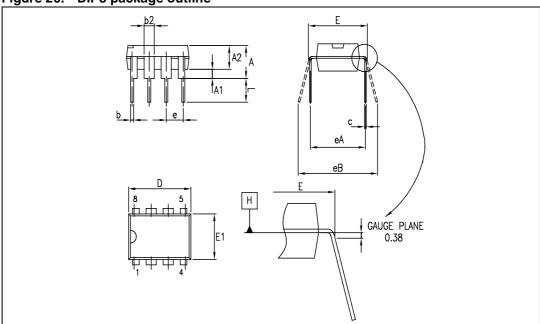


Table 5. DIP8 package mechanical data

	Dimensions								
Symbol		Millimeters			Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.			
Α			5.33			0.210			
A1	0.38			0.015					
A2	2.92	3.30	4.95	0.115	0.130	0.195			
b	0.36	0.46	0.56	0.014	0.018	0.022			
b2	1.14	1.52	1.78	0.045	0.060	0.070			
С	0.20	0.25	0.36	0.008	0.010	0.014			
D	9.02	9.27	10.16	0.355	0.365	0.400			
Е	7.62	7.87	8.26	0.300	0.310	0.325			
E1	6.10	6.35	7.11	0.240	0.250	0.280			
е		2.54			0.100				
eA		7.62			0.300				
eB			10.92			0.430			
L	2.92	3.30	3.81	0.115	0.130	0.150			

Note:

Dimensions "D" and "E1" do not include mold flash, protrusions or gate burrs. Mold flash, protrusions or gate burrs shall not exceed 0.25 mm in total (both sides). Datum plane "H" coincides with the bottom of the lead, where the lead exits the body.

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5.2 SO-8 package information

Figure 21. SO-8 package outline

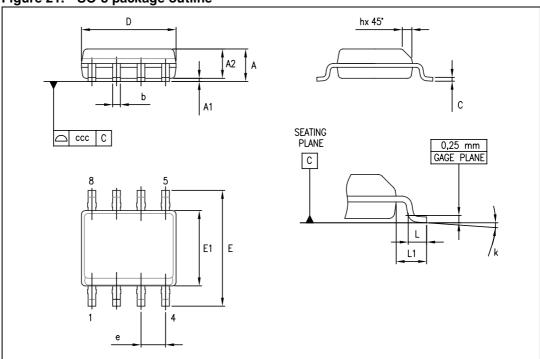


Table 6. SO-8 package mechanical data

	Dimensions							
Symbol		Millimeters		Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.		
Α			1.75			0.069		
A1	0.10		0.25	0.004		0.010		
A2	1.25			0.049				
b	0.28		0.48	0.011		0.019		
С	0.17		0.23	0.007		0.010		
D	4.80	4.90	5.00	0.189	0.193	0.197		
E	5.80	6.00	6.20	0.228	0.236	0.244		
E1	3.80	3.90	4.00	0.150	0.154	0.157		
е		1.27			0.050			
h	0.25		0.50	0.010		0.020		
L	0.40		1.27	0.016		0.050		
L1		1.04			0.040			
k	0		8°	1°		8°		
ccc			0.10			0.004		

6 Ordering information

Table 7. Order codes

Part number	Temperature range	Package	Packaging	Marking
TL062IN TL062AIN TL062BIN	-40 °C, +105 °C	DIP8	Tube	TL062IN TL062AIN TL062BIN
TL062ID/IDT TL062AID/AIDT TL062BID/BIDT	-40 C, +105 C	SO-8	Tube or tape and reel	062I 062AI 062BI
TL062CN TL062ACN TL062BCN	52ACN DIP8		Tube	TL062CN TL062ACN TL062BCN
TL062CD/CDT TL062ACD/ACDT TL062BCD/BCDT	0 °C, +70 °C	SO-8	Tube or tape and reel	062C 062AC 062BC

7 Revision history

Table 8. Document revision history

Date	Revision	Changes
28-Mar-2001	1	Initial release.
27-Jul-2007	2	Added values for R _{thja} and R _{thjc} in <i>Table 1: Absolute maximum ratings</i> . Added <i>Table 2: Operating conditions</i> . Updated format.
15-Mar-2010	3	Updated document format. Added TL062A and TL062B in title on cover page. Updated package information in <i>Chapter 5</i> .
21-Sep-2012	4	Removed TL062M, AM, BM /TL062I, AI, BI / TL062C, AC, BC part numbers and temperature ranges from <i>Table 1</i> . and TL062M, AM, BM from <i>Table 2</i> . Removed TL062M, updated min. "Input common mode voltage range" for TL062C device in <i>Table 3</i> . Removed TL062AM and TL062BM devices, updated max. "Input offset voltage - T _{amb} " for TL062AC, AI devices in <i>Table 4</i> . Removed TL062MN, TL062AMN, TL062BMN, TL062BMD/MDT, TL062AMD/AMDT, TL062BMD/BMDT part numbers from <i>Table 7</i> . Minor corrections throughout document.

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